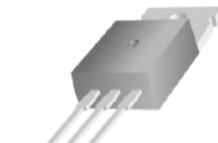


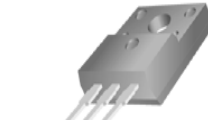
High Voltage NPN Power Transistor

Features

- High Voltage
- High Switch Speed
- $BV_{CEO} : 400V$
- $BV_{CBO} : 700V$
- $I_c : 8A$
- $V_{CE(SAT)} : 3V @ I_c / I_B = 8A / 2A$



TO-220
Pin Definition
1. Base
2. Collector
3. Emitter

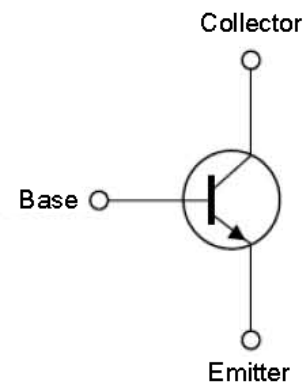


TO-220F
Pin Definition
1. Base
2. Collector
3. Emitter

Application

- Electronic Ballasts
- Adapter
- Lighting

INTERNAL SCHEMATIC DIAGRAM



ABSOLUTE MAXIMUM RATINGS ($T_c = 25^{\circ}C$)

Parameter	Symbol	Max rating	Unit
Collector-Base Voltage	V_{CBO}	700	V
Collector-Emitter Voltage	V_{CEO}	400	V
Emitter-Base Voltage	V_{EBO}	9	V
Collector Current (DC)	I_c	8	A
Collector Current (Pulse)		16	A
Base Current (DC)	I_B	4	A
Base Current (Pulse)		8	A
Total Power Dissipation (TO-220)	P_D	75	W
Total Power Dissipation (TO-220F)	P_D	30	W
Junction Temperature	T_J	+150	$^{\circ}C$
Operating Junction and Storage Temperature Range	T_{STG}	-55 ~ +150	$^{\circ}C$

Note: Single Pulse. $P_w=300\mu S$, Duty $\leq 2\%$

ELECTRICAL CHARACTERISTICS (T_c = 25°C)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Collector-Base Voltage	BVCBO	IC = 1mA, IB=0	700	–	–	V
Collector-Emitter Breakdown Voltage	BVCEO	IC = 10mA, IE=0	400	–	–	V
Emitter- Base Breakdown Voltage	BVEBO	IE = 1mA, IC=0	9	–	–	V
Collector Cutoff Current	ICEO	VCE = 400V, IB=0	–	–	1	mA
Collector Cutoff Current	ICBO	VCB = 700V, IE=0	–	–	1	mA
Emitter Cutoff Current	IEBO	VEB = 9V, IC=0	–	–	1	mA
DC Current Gain	hFE1	VCE = 5V, IC=2A	20	–	40	
	hFE2	VCE = 5V, IC=5A	5	–	30	
Collector-Emitter Saturation Voltage	VCE(SAT1)	IC =2A, IB =0.4A	–	–	1	V
	VCE(SAT2)	IC = 5A, IB =1A	–	–	1.5	
	VCE(SAT3)	IC = 8A, IB =2A	–	–	3	
Base-Emitter Saturation Voltage	VBE(SAT1)	IC = 2A, IB =0.4A	–	–	1.2	V
	VBE(SAT2)	IC = 5A, IB =1A	–	–	1.6	

Dynamic

Frequency	f _T	VCE = 10V, IC=0.5A	4	–	–	MHz
Output Capacitance	Cob	VCB = 10V, f=0.1MHz	–	180	–	pF

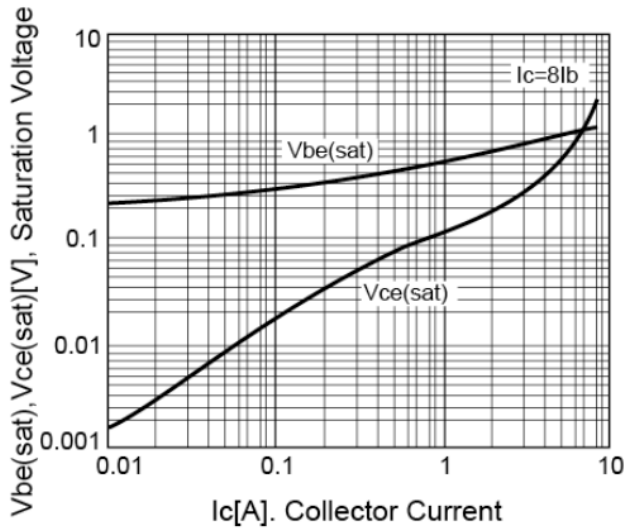
Resistive Load Switching Time (Ratings)

Delay Time	t _d	V _{cc} =125V, IC=5A, IB1=1A, IB2=1A, tp=25uS Duty Cycle ≤ 2%	–	0.06	0.1	uS
Rise Time	t _r		–	0.45	1	uS
Storage Time	t _{STG}		–	2.8	3	uS
Fall Time	t _f		–	0.3	0.7	uS

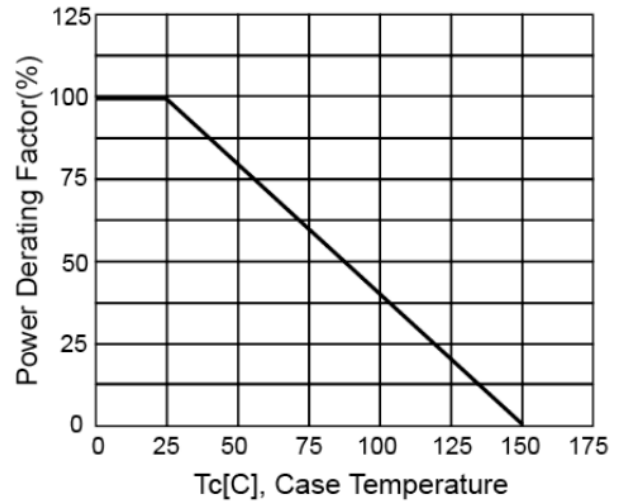
Note: Pulse test: pulse width ≤ 300uS, duty cycle ≤ 2%

Electrical Characteristics Curve (Ta = 25°C, unless otherwise noted)

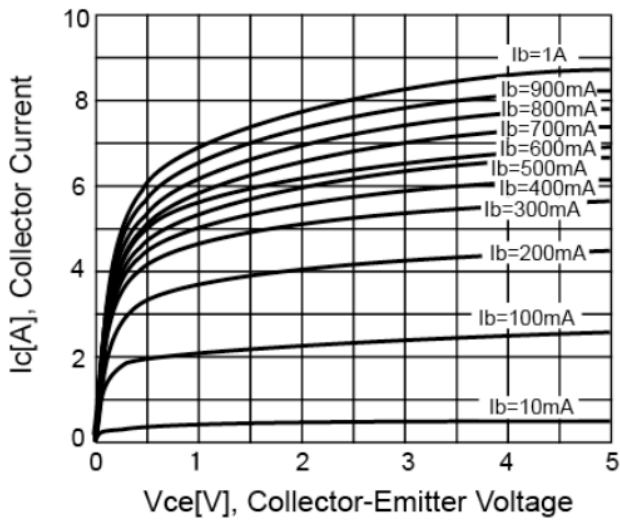
V_{CE(sat)} V.S. V_{BE(sat)}



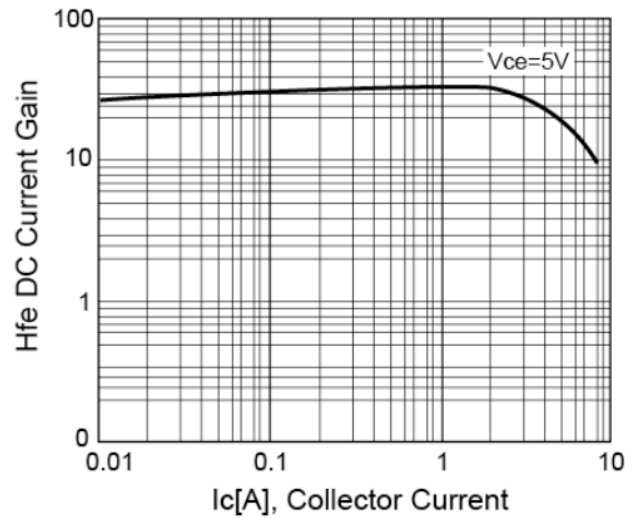
Power Derating



Static Characteristics



DC Current Gain



Ordering Information

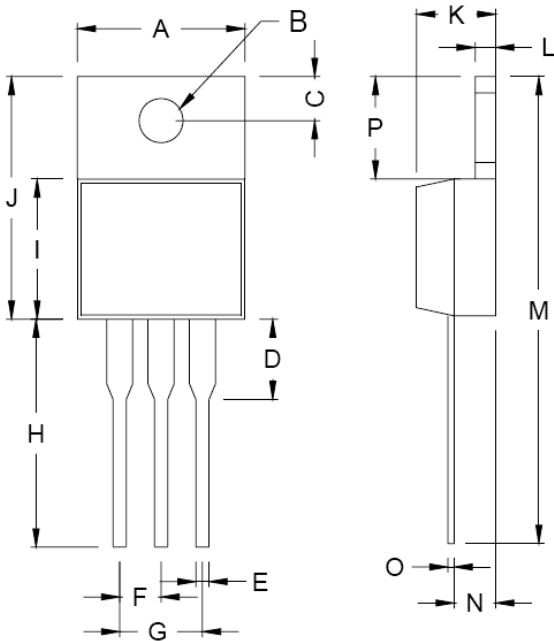
Type NO	Marking	Package Code
WTX13007	13007	TO-220

Marking and Pin Define



First Line	WTC	Company Name	
Second Line	13007	Product Code	
Third Line	BB0TX	1st (Year Code)	A-2010 B-2011 C-2012 D-2013 ...
		2nd (Month Code)	A-Jan, B-Feb, C-Mar, D-Apr, E-May, F-Jun, G-Jul, H-Aug, I-Sep, J-Oct, K-Nov, L-Dec
		3rd (Lot Code)	0-9, A-Z
		4th (Product Code)	M - MOS, T - Transistor, L - Linear
		5th (Package Code)	I - TO251, D - TO252, L - TO92, M - TO126, X - TO220, F - TO220F, Y - SOT89, S - SOP8
		6th (Spec Code)	(Reserve)

TO-220 Package Dimension

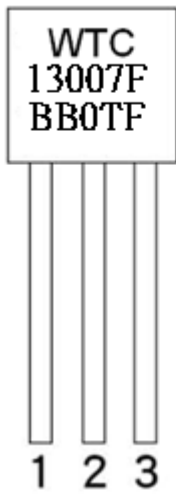


DIM	TO-220 DIMENSION			
	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	10.000	10.500	0.394	0.413
B	3.740	3.910	0.147	0.154
C	2.440	2.940	0.096	0.116
D	-	6.350	-	0.250
E	0.381	1.106	0.015	0.040
F	2.345	2.715	0.092	0.058
G	4.690	5.430	0.092	0.107
H	12.700	14.732	0.500	0.581
J	14.224	16.510	0.560	0.650
K	3.556	4.826	0.140	0.190
L	0.508	1.397	0.020	0.055
M	27.700	29.620	1.060	1.230
N	2.032	2.921	0.080	0.115
O	0.255	0.610	0.010	0.024
P	5.842	6.858	0.230	0.270

Ordering Information

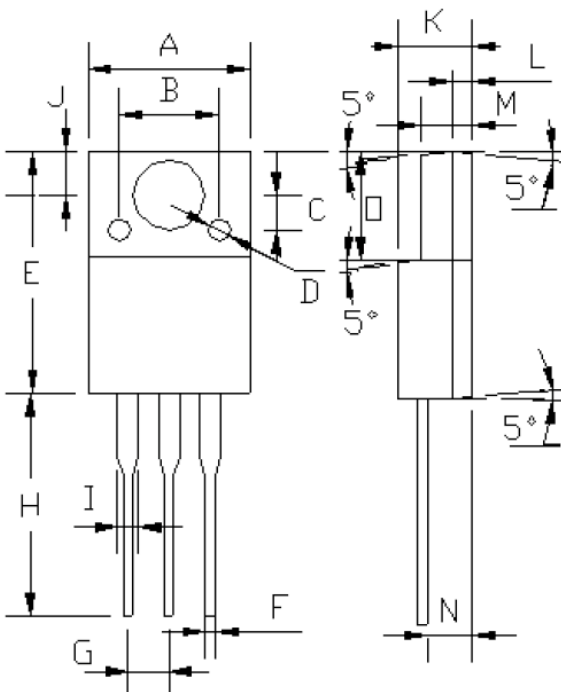
Type NO	Marking	Package Code
WTF13007	13007F	TO-220F

Marking and Pin Define



First Line	WTC	Company Name	
Second Line	13007F	Product Code	
Third Line	BB0TF	1st (Year Code)	A-2010 B-2011 C-2012 D-2013 ...
		2nd (Month Code)	A-Jan, B-Feb, C-Mar, D-Apr, E-May, F-Jun, G-Jul, H-Aug, I-Sep, J-Oct, K-Nov, L-Dec
		3rd (Lot Code)	0-9, A-Z
		4th (Product Code)	M - MOS, T - Transistor, L - Linear
		5th (Package Code)	I - TO251, D - TO252, L - TO92, M - TO126, X - TO220, F - TO220F, Y - SOT89, S - SOP8
		6th (Spec Code)	(Reserve)

TO-220F Package Dimension



DIM	220F DIMENSION			
	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	9.96	10.36	0.392	0.407
B	6.20 (typ.)		0.244 (typ.)	
C	2.20 (typ.)		0.087 (typ.)	
D	1.40 (typ.)		0.055 (typ.)	
E	15.07	16.07	0.593	0.632
F	0.80 (typ.)		0.031 (typ.)	
G	2.44	2.64	0.096	0.104
H	13.08	13.48	0.514	0.530
I	1.47 (max.)		0.057 (max.)	
J	3.20	3.40	0.125	0.133
K	4.60	4.80	0.181	0.188
L	1.15 (typ.)		0.045 (typ.)	
M	2.44	2.64	0.096	0.104
N	2.60	2.80	0.102	0.110
O	6.55	6.65	0.258	0.262